



CAT5115

32-Tap Digitally Programmable Potentiometer (DPP™)



FEATURES

- 32-position, linear-taper potentiometer
- Low power CMOS technology
- Single supply operation: 2.5V-5.5V
- Increment up/down serial interface
- Resistance values: 10kΩ, 50kΩ and 100kΩ
- Available in PDIP, SOIC, TSSOP and MSOP packages

APPLICATIONS

- Automated product calibration
- Remote control adjustments
- Offset, gain and zero control
- Tamper-proof calibrations
- Contrast, brightness and volume controls
- Motor controls and feedback systems
- Programmable analog functions

DESCRIPTION

The CAT5115 is a single digitally programmable potentiometer (DPP™) designed as an electronic replacement for mechanical potentiometers and trim pots. Ideal for automated adjustments on high volume production lines, they are also well suited for applications where equipment requiring periodic adjustment is either difficult to access or located in a hazardous or remote environment.

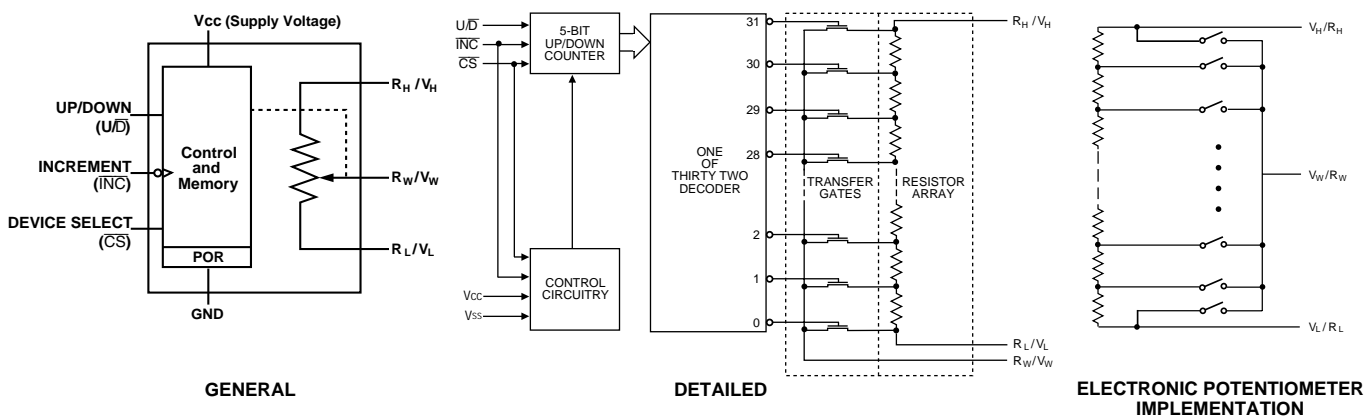
The CAT5115 contains a 32-tap series resistor array connected between two terminals R_H and R_L . An up/down counter and decoder that are controlled by three input pins, determines which tap is connected to the wiper, R_W . The wiper is always set to the mid point, tap 15 at power up. The tap position is not stored in memory. Wiper-control of the CAT5115 is accomplished with three input control pins, \overline{CS} , U/\overline{D} , and \overline{INC} . The \overline{INC} input increments the wiper in the direction which is

determined by the logic state of the U/\overline{D} input. The \overline{CS} input is used to select the device.

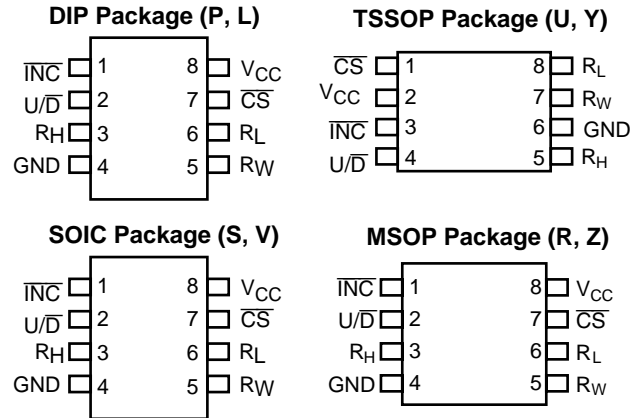
The digitally programmable potentiometer can be used as a three-terminal resistive divider or as a two-terminal variable resistor. DPPs bring variability and programmability to a wide variety of applications including control, parameter adjustments, and signal processing.

For a pin-compatible device that recalls a stored tap position on power-up refer to the CAT5114 data sheet.

FUNCTIONAL DIAGRAM



PIN CONFIGURATION



PIN FUNCTIONS

| Pin Name | Function |
|-----------------|------------------------------|
| INC | Increment Control |
| U/D | Up/Down Control |
| R _H | Potentiometer High Terminal |
| GND | Ground |
| R _W | Potentiometer Wiper Terminal |
| R _L | Potentiometer Low Terminal |
| CS | Chip Select |
| V _{CC} | Supply Voltage |

PIN DESCRIPTIONS

INC: Increment Control Input

The INC input moves the wiper in the up or down direction determined by the condition of the U/D input.

U/D: Up/Down Control Input

The U/D input controls the direction of the wiper movement. When in a high state and CS is low, any high-to-low transition on INC will cause the wiper to move one increment toward the R_H terminal. When in a low state and CS is low, any high-to-low transition on INC will cause the wiper to move one increment towards the R_L terminal.

R_H: High End Potentiometer Terminal

R_H is the high end terminal of the potentiometer. It is not required that this terminal be connected to a potential greater than the R_L terminal. Voltage applied to the R_H terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND.

R_W: Wiper Potentiometer Terminal

R_W is the wiper terminal of the potentiometer. Its position on the resistor array is controlled by the control inputs, INC, U/D and CS. Voltage applied to the R_W terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND.

R_L: Low End Potentiometer Terminal

R_L is the low end terminal of the potentiometer. It is not required that this terminal be connected to a potential less than the R_H terminal. Voltage applied to the R_L terminal cannot exceed the supply voltage, V_{CC} or go below ground, GND. R_L and R_H are electrically interchangeable.

CS: Chip Select

The chip select input is used to activate the control input of the CAT5115 and is active low. When in a high state, activity on the INC and U/D inputs will not affect or change the position of the wiper.

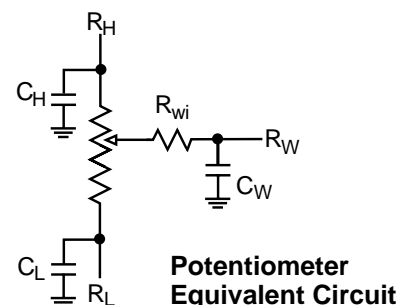
DEVICE OPERATION

The CAT5115 operates like a digitally controlled potentiometer with R_H and R_L equivalent to the high and low terminals and R_W equivalent to the mechanical potentiometer's wiper. There are 32 available tap positions including the resistor end points, R_H and R_L. There are 31 resistor elements connected in series between the R_H and R_L terminals. The wiper terminal is connected to one of the 32 taps and controlled by three inputs, INC, U/D and CS. These inputs control a five-bit up/down counter whose output is decoded to select the wiper position.

With CS set LOW the CAT5115 is selected and will respond to the U/D and INC inputs. HIGH to LOW transitions on INC will increment or decrement the wiper (depending on the state of the U/D input and five-bit counter). The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. When the CAT5115 is powered-down, the wiper position is reset. When power is restored, the counter is set to the mid point, tap 15.

OPERATION MODES

| $\overline{\text{INC}}$ | $\overline{\text{CS}}$ | $\text{U}/\overline{\text{D}}$ | Operation |
|-------------------------|------------------------|--------------------------------|----------------|
| High to Low | Low | High | Wiper toward H |
| High to Low | Low | Low | Wiper toward L |
| X | High | X | Standby |



ABSOLUTE MAXIMUM RATINGS

Supply Voltage

 V_{CC} to GND -0.5V to +7V

Inputs

 $\overline{\text{CS}}$ to GND -0.5V to $V_{CC} + 0.5V$ $\overline{\text{INC}}$ to GND -0.5V to $V_{CC} + 0.5V$ $\text{U}/\overline{\text{D}}$ to GND -0.5V to $V_{CC} + 0.5V$ H to GND -0.5V to $V_{CC} + 0.5V$ L to GND -0.5V to $V_{CC} + 0.5V$ W to GND -0.5V to $V_{CC} + 0.5V$

Operating Ambient Temperature

Industrial ('I' suffix) -40°C to +85°C

Junction Temperature +150°C

Storage Temperature -65°C to +150°C

Lead Soldering (10 sec max) +300°C

* Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Absolute Maximum Ratings are limited values applied individually while other parameters are within specified operating conditions, and functional operation at any of these conditions is NOT implied. Device performance and reliability may be impaired by exposure to absolute rating conditions for extended periods of time.

RELIABILITY CHARACTERISTICS

| Symbol | Parameter | Test Method | Min | Typ | Max | Units |
|--------------------|--------------------|-------------------------------|-----------|-----|-----|--------|
| $V_{ZAP}^{(1)}$ | ESD Susceptibility | MIL-STD-883, Test Method 3015 | 2000 | | | Volts |
| $I_{LTH}^{(1)(2)}$ | Latch-Up | JEDEC Standard 17 | 100 | | | mA |
| T_{DR} | Data Retention | MIL-STD-883, Test Method 1008 | 100 | | | Years |
| N_{END} | Endurance | MIL-STD-883, Test Method 1003 | 1,000,000 | | | Stores |

DC Electrical Characteristics: $V_{CC} = +2.5V$ to $+5.5V$ unless otherwise specified

Power Supply

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---------------|----------------------------|--|-----|-----|-----------|---------|
| V_{CC} | Operating Voltage Range | | 2.5 | — | 5.5 | V |
| I_{CC1} | Supply Current (Increment) | $V_{CC} = 5.5V, f = 1MHz, I_W = 0$ $V_{CC} = 5.5V, f = 250kHz, I_W = 0$ | — | — | 100 50 | μA |
| $ISB_1^{(2)}$ | Supply Current (Standby) | $CS = V_{CC} - 0.3V$ $U/D, INC = V_{CC} - 0.3V$ or GND | — | — | 1 | μA |

Logic Inputs

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|-----------|-------------------------------|------------------------------|---------------------|-----|---------------------|---------|
| I_{IH} | Input Leakage Current | $V_{IN} = V_{CC}$ | — | — | 10 | μA |
| I_{IL} | Input Leakage Current | $V_{IN} = 0V$ | — | — | -10 | μA |
| V_{IH1} | TTL High Level Input Voltage | $4.5V \leq V_{CC} \leq 5.5V$ | 2 | — | V_{CC} | V |
| V_{IL1} | TTL Low Level Input Voltage | | 0 | — | 0.8 | V |
| V_{IH2} | CMOS High Level Input Voltage | $2.5V \leq V_{CC} \leq 5.5V$ | $V_{CC} \times 0.7$ | — | $V_{CC} + 0.3$ | V |
| V_{IL2} | CMOS Low Level Input Voltage | | -0.3 | — | $V_{CC} \times 0.2$ | V |

- NOTES:**
- (1) This parameter is tested initially and after a design or process change that affects the parameter.
 - (2) Latch-up protection is provided for stresses up to 100mA on address and data pins from -1V to $V_{CC} + 1V$
 - (3) I_W =source or sink
 - (4) These parameters are periodically sampled and are not 100% tested.

Potentiometer Parameters

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|--|-------------------------------|--|-----|--------|-----------------|--------|
| R _{POT} | Potentiometer Resistance | -10 Device | | 10 | | kΩ |
| | | -50 Device | | 50 | | |
| | | -00 Device | | 100 | | |
| | Pot Resistance Tolerance | | | | ± 20 | % |
| V _{RH} | Voltage on R _H pin | | 0 | | V _{CC} | V |
| V _{RL} | Voltage on R _L pin | | 0 | | V _{CC} | V |
| | Resolution | | | 3.2 | | % |
| INL | Integral Linearity Error | I _w ≤ 2μA | | 0.5 | 1 | LSB |
| DNL | Differential Linearity Error | I _w ≤ 2μA | | 0.25 | 0.5 | LSB |
| R _{wi} | Wiper Resistance | V _{CC} = 5V, I _w = 1mA | | | 400 | Ω |
| | | V _{CC} = 2.5V, I _w = 1mA | | | 1 | kΩ |
| I _w | Wiper Current | | | | 1 | mA |
| TC _{R_{POT}} | TC of Pot Resistance | | | 300 | | ppm/°C |
| TC _{R_{RATIO}} | Ratiometric TC | | | | 20 | ppm/°C |
| V _N | Noise | 100kHz / 1kHz | | 8/24 | | nV/√Hz |
| C _H /C _L /C _W | Potentiometer Capacitances | | | 8/8/25 | | pF |
| fc | Frequency Response | Passive Attenuator, 10kΩ | | 1.7 | | MHz |

AC CONDITIONS OF TEST

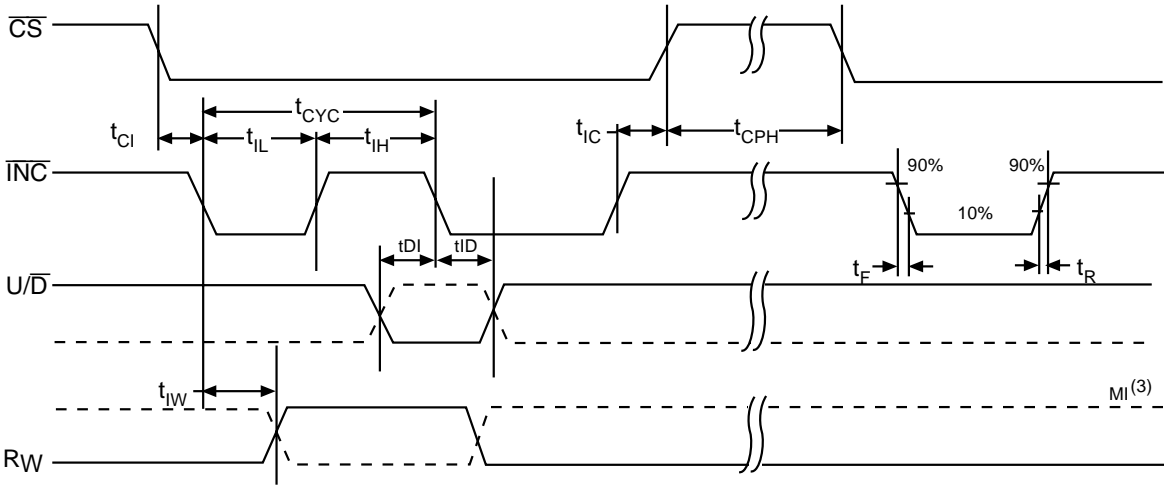
| | |
|---------------------------|--|
| V _{CC} Range | 2.5V ≤ V _{CC} ≤ 5.5V |
| Input Pulse Levels | 0.2V _{CC} to 0.7V _{CC} |
| Input Rise and Fall Times | 10ns |
| Input Reference Levels | 0.5V _{CC} |

AC OPERATING CHARACTERISTICS:

V_{CC} = +2.5V to +5.5V, V_H = V_{CC}, V_L = 0V, unless otherwise specified

| Symbol | Parameter | Min | Typ ⁽¹⁾ | Max | Units |
|--|---|-----|--------------------|-----|-------|
| t _{CI} | \overline{CS} to INC Setup | 100 | — | — | ns |
| t _{DI} | U/D to \overline{INC} Setup | 50 | — | — | ns |
| t _{ID} | U/D to \overline{INC} Hold | 100 | — | — | ns |
| t _{IL} | \overline{INC} LOW Period | 250 | — | — | ns |
| t _{IH} | \overline{INC} HIGH Period | 250 | — | — | ns |
| t _{IC} | \overline{INC} Inactive to \overline{CS} Inactive | 1 | — | — | μs |
| t _{CPH} | \overline{CS} Deselect Time | 100 | — | — | ns |
| t _{IW} | \overline{INC} to V _{OUT} Change | — | 1 | 5 | μs |
| t _{CYC} | \overline{INC} Cycle Time | 1 | — | — | μs |
| t _R , t _F ⁽²⁾ | \overline{INC} Input Rise and Fall Time | — | — | 500 | μs |
| t _{PU} ⁽²⁾ | Power-up to Wiper Stable | — | — | 1 | msec |

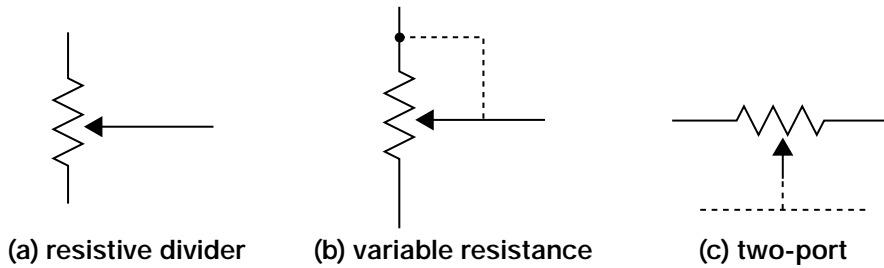
A. C. TIMING



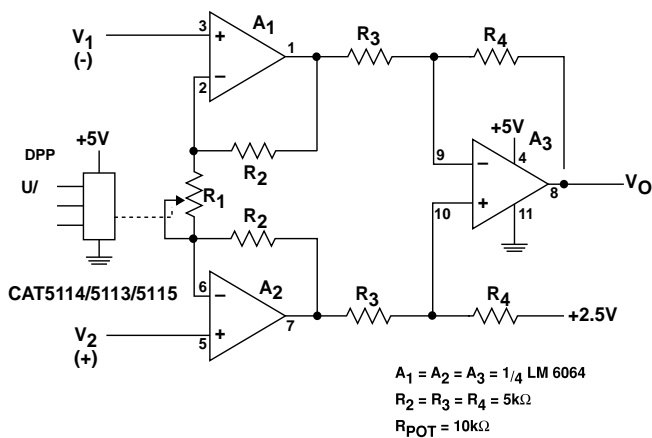
(1) Typical values are for T_A=25°C and nominal supply voltage.
 (2) This parameter is periodically sampled and not 100% tested.
 (3) MI in the A.C. Timing diagram refers to the minimum incremental change in the W output due to a change in the wiper position.

APPLICATIONS INFORMATION

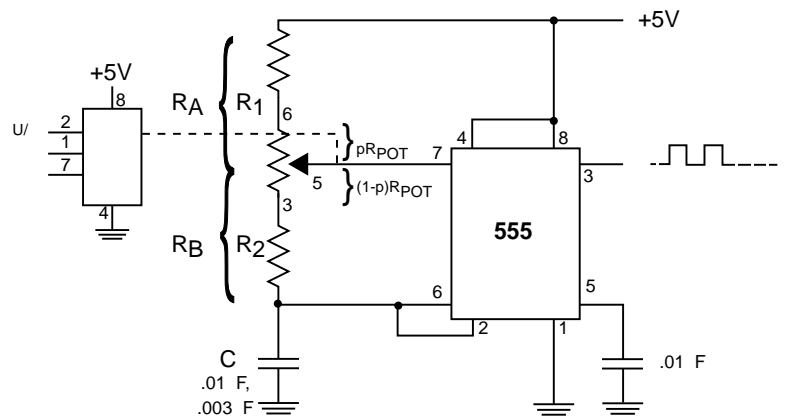
Potentiometer Configurations



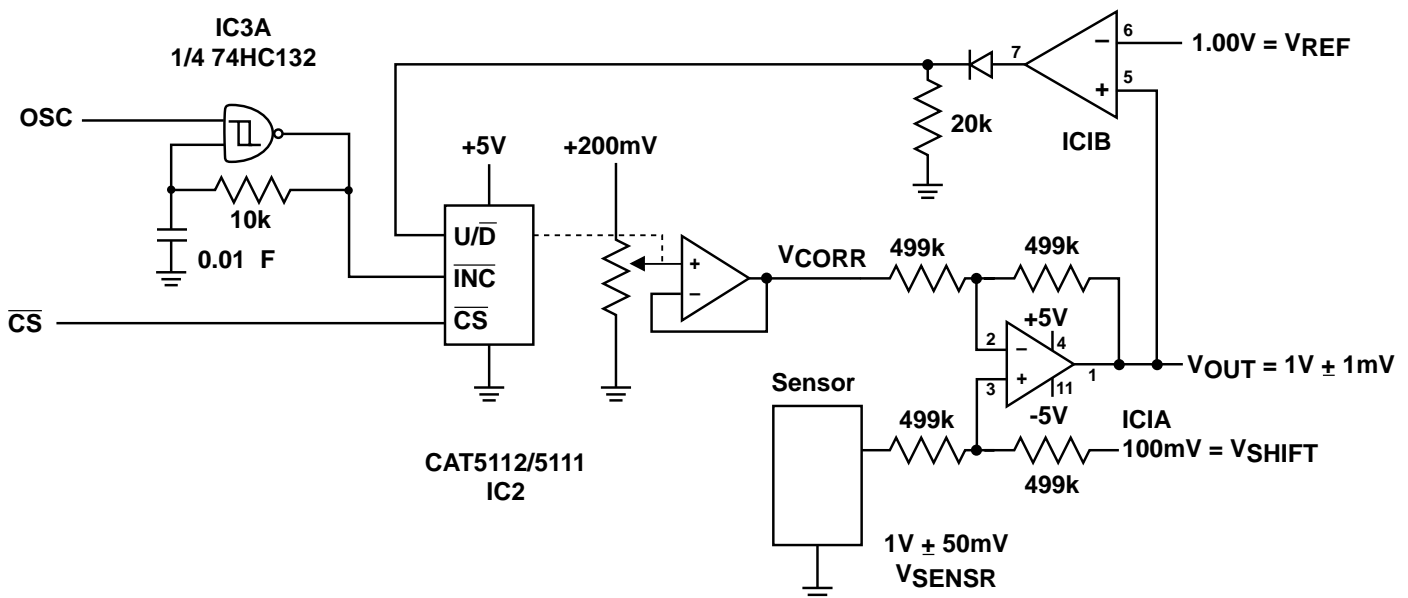
Applications



Programmable Instrumentation Amplifier

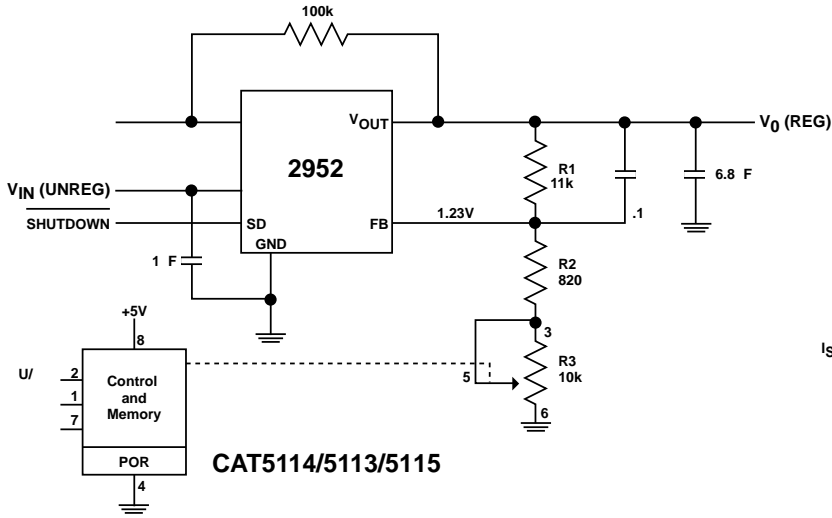


Programmable Sq. Wave Oscillator (555)

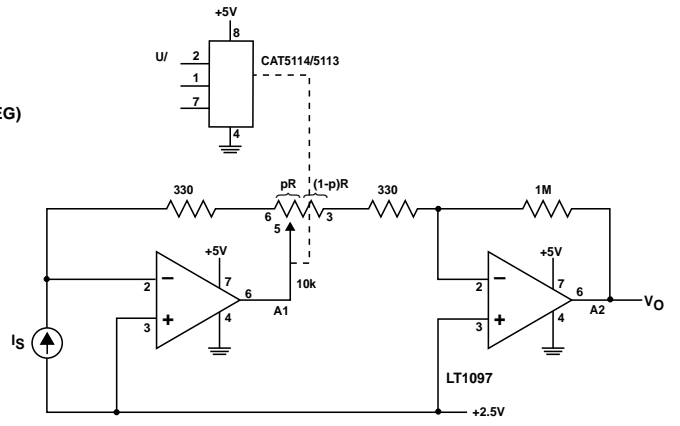


Sensor Auto Referencing Circuit

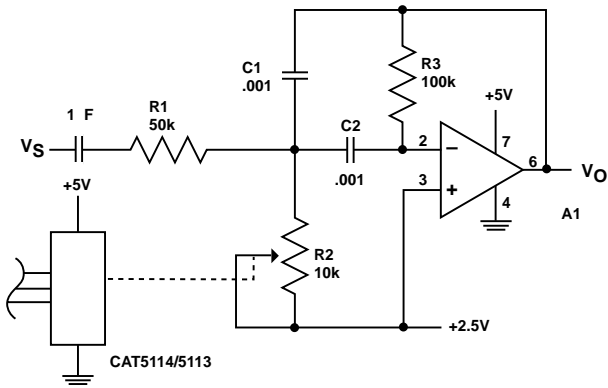
APPLICATIONS INFORMATION



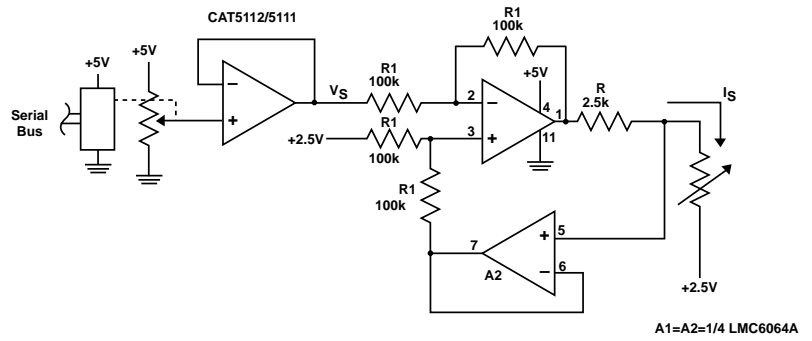
Programmable Voltage Regulator



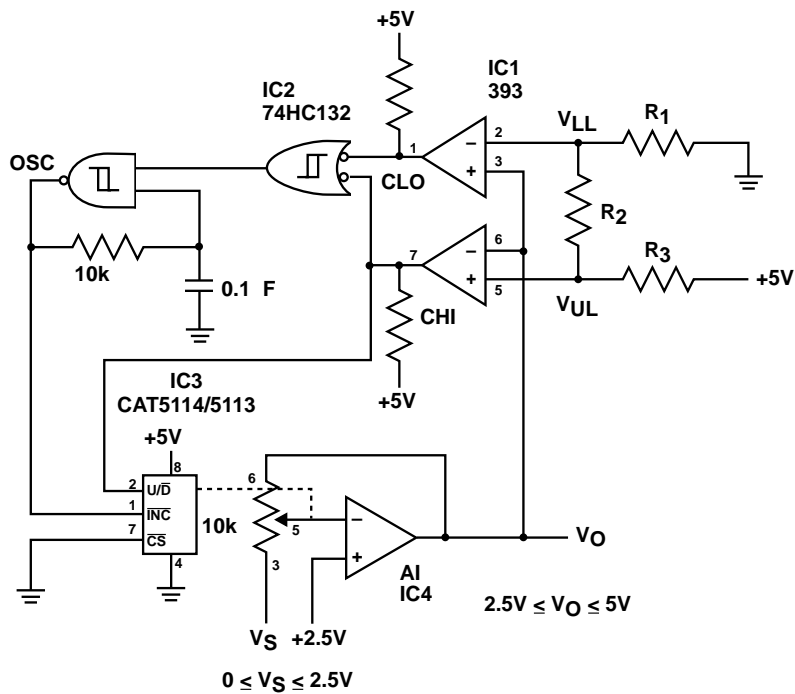
Programmable I to V convertor



Programmable Bandpass Filter

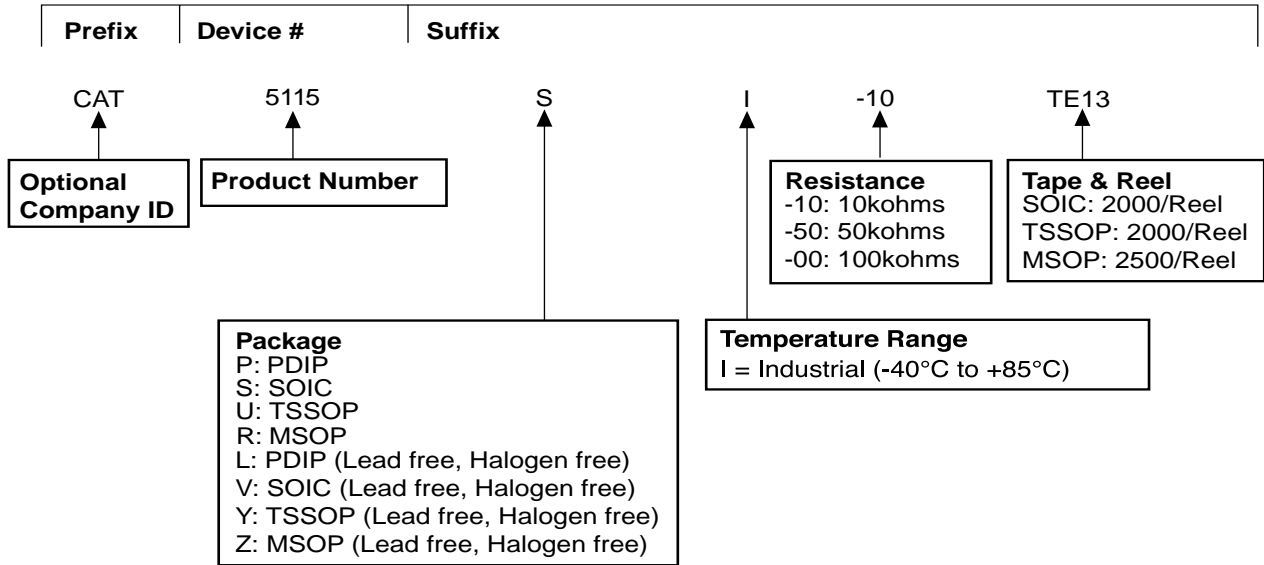


Programmable Current Source/Sink



Automatic Gain Control

ORDERING INFORMATION



REVISION HISTORY

| Date | Rev. | Reason |
|-----------|------|---|
| 9/25/2003 | B | Changed designation to Preliminary Updated Description Updated Potentiometer Parameters table |
| 3/10/2004 | C | Updated Potentiometer Parameters table |
| 3/29/2004 | D | Changed Green Package marking for SOIC from W to V |
| 4/12/2004 | E | Updated Reel Ordering Information |
| 8/31/2004 | F | Deleted ICC2 from DC Characteristics table Updated AC Operating Characteristics table Updated A.C. Timing diagram |

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